



DOCKET NO. PHUS010610

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Letavic et al.) Examiner: Lewis, M.
Application No.: 10/015,847)
Filed: 12/10/2001)
For: DUAL GATE OXIDE HIGH-VOLTAGE)
SEMICONDUCTOR DEVICE)
(as Amended))

8/8 Amend
w/ Way
3-11-03
A. Waller

Commissioner for Patents
Washington D.C. 20231

AMENDMENT

Sir:

In response to the Office Action of December 19, 2002, please amend the application as follows:

In the Drawings

Please amend FIG. 1 and FIG. 2 as indicated in red in the attached Submission of Proposed Drawing Amendment for Approval of Examiner.

RECEIVED
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